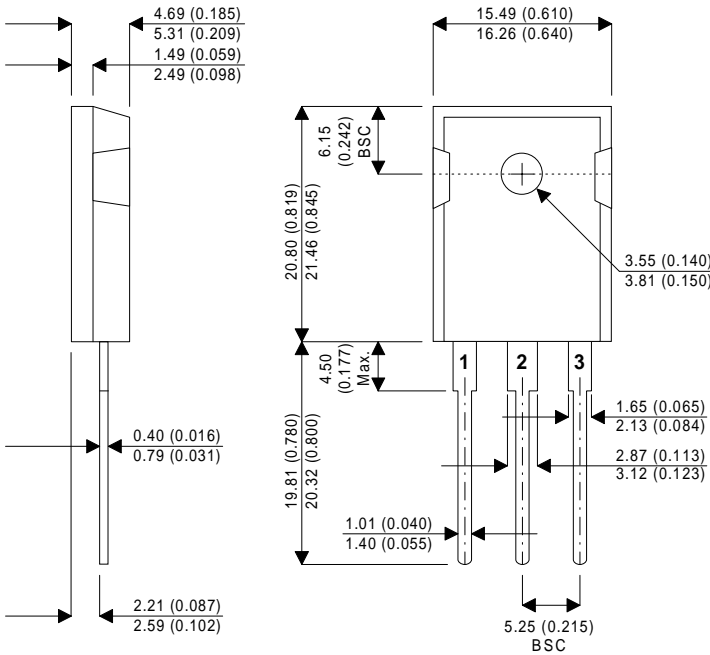


MECHANICAL DATA

Dimensions in mm



TO247

Pin 1 – Base Pad 2 – Collector Pad 3 – Emitter

NPN MULTI-EPITAXIAL TRANSISTOR

FEATURES

- DIFFUSED BY SEMEFAB
- VERY LOW SATURATION VOLTAGES
- VERY FAST SWITCHING (t = 60ns)
- HIGH RELIABILITY

APPLICATIONS

- HIGH FREQUENCY AND HIGH EFFICIENCY CONVERTERS
- SWITCHING REGULATORS
- MOTOR CONTROLS

The BUP56 is a very fast switching, very low saturation, high power transistor using wafer diffused by Semefab. It is particularly suited to applications requiring efficient, fast switching devices.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

| | | |
|--------------------|---|--------------|
| V _{CEX} | Collector – Emitter Voltage (V _{BE} = -1.5V) | 150V |
| V _{CEO} | Collector – Emitter Voltage (I _B = 0) | 60V |
| V _{EBO} | Emitter – Base Voltage | 10V |
| I _C | Collector Current | 30A |
| I _{C(PK)} | Peak Collector Current | 40A |
| P _{tot} | Total Dissipation at T _{case} = 25°C | 150W |
| T _{stg} | Storage Temperature | -55 to 175°C |
| T _J | Maximum Operating Junction Temperature | 175°C |
| R _{th} | Thermal Resistance (junction-case) | 1.0°C/W |

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

| Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--|--|------|------|----------|------|
| $V_{CEO(sus)}$ Collector Emitter Sustaining Voltage | $I_C = 100mA$ | 60 | | | V |
| I_{CEX} Collector Cut-Off Current | $V_{BE} = -1.5V$ $V_{CEX} = 154$ $T_C = 150^{\circ}C$ | | | 0.1 5 | mA |
| I_{EBO} Emitter Cut-Off Current | $V_{BE} = 8V$ | | | 0.1 | mA |
| $V_{CE(sat)^*}$ Collector – Emitter Saturation Voltage | $I_C = 15A$ $I_B = 1.5A$ | | 0.4 | 0.7 | V |
| | $I_C = 30A$ $I_B = 3A$ | | 0.7 | 1.0 | |
| $V_{BE(sat)}$ Base – Emitter Saturation Voltage | $I_C = 15A$ $I_B = 1.5A$ | | 1.1 | 1.4 | V |
| | $I_C = 30A$ $I_B = 3A$ | | 1.4 | 1.7 | |
| h_{FE} DC Current Gain | $I_C = 15A$ $V_{CE} = 4V$ | 25 | 30 | | — |
| | $I_C = 30A$ $V_{CE} = 4V$ | 15 | 22 | | |

SWITCHING CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

| | | | | | |
|--------------------|--|--|-----|------|---------|
| t_{on} On Time | $I_C = 20A$ $V_{CC} = 60V$ $I_{B1} = 2A$ $I_{B2} = 2A$ | | 0.2 | 0.5 | μS |
| t_s Storage Time | | | | 0.7 | |
| t_f Fall Time | | | | 0.15 | |